

INCHANGE SEMICONDUCTOR

isc Silicon PNP Power Transistors

3CD9F

DESCRIPTION

- Low Collector Saturation Voltage-
- : V_{CE(sat)}= -1.5V(Max.)@ I_C= -7.5A
- DC Current Gain-
- : h_{FE} =15-120@I_C= -7.5A,, V_{CE}=-5V
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

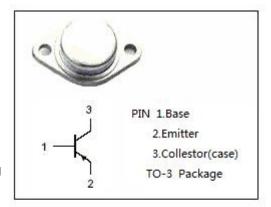
Designed for general-purpose power amplifier and switching applications

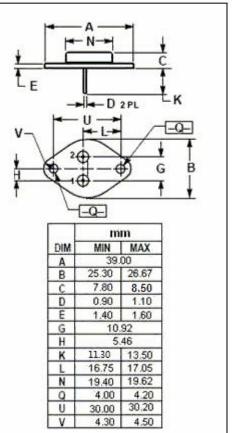
ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

| SYMBOL | PARAMETER | VALUE | UNIT |
|------------------|------------------------------|-------|------|
| V _{CBO} | Collector-Base Voltage | -300 | V |
| V _{CEO} | Collector-Emitter Voltage | -300 | V |
| V_{EBO} | Emitter-Base Voltage | -5 | V |
| lc | Collector Current-Continuous | -15 | А |
| Pc | Collector Power Dissipation | 150 | W |
| TJ | Junction Temperature 175 | | °C |
| T _{stg} | Storage Temperature -55~175 | | °C |

THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | МАХ | UNIT |
|---------------------|--------------------------------------|------|------|
| R _{th j-c} | Thermal Resistance, Junction to Case | 0.66 | °C/W |







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ELECTRICAL CHARACTERISTICS

$T_c=25^{\circ}C$ unless otherwise specified

| SYMBOL | PARAMETER | CONDITIONS | MIN | МАХ | UNIT |
|-----------------------|--------------------------------------|--|------|------|------|
| Vceo(br) | Collector-Emitter Breakdown Voltage | I _C =- 5mA ; I _B = 0 | -300 | | V |
| V _{CE} (sat) | Collector-Emitter Saturation Voltage | I _C =- 7.5A; I _B = 0.75A | | -1.5 | V |
| V _{BE(sat)} | Base-Emitter Saturation Voltage | I _C = -7.5A; I _B = 0.75A | | -1.8 | V |
| I _{CEO} | Collector Cutoff Current | V _{CE} =- 300V; I _B = 0 | | -2.0 | mA |
| I _{СВО} | Collector Cutoff Current | V _{CB} =- 300V; I _E = 0 | | -1.0 | mA |
| I _{EBO} | Emitter Cutoff Current | V _{EB} = -5V; I _C = 0 | | -1.0 | mA |
| h _{FE} | DC Current Gain | I _C = -7.5A; V _{CE} = -5V | 15 | 120 | |

NOTICE:

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